imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

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Contact us

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D

DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead Free By Design/RoHS Compliant (Note 1)
- "Green" Device (Note 2)
- ESD Protected Up To 2KV
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: TSSOP-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Weight: 0.039 grams (approximate)





ESD PROTECTED TO 2kV

Top View Bottom View

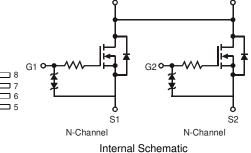




D S2

S2

G2



D

Ordering Information (Note 3)

Part Number	Case	Packaging
DMG6968UTS-13	TSSOP-8	2500 / 13" Tape & Reel

2

3

S1

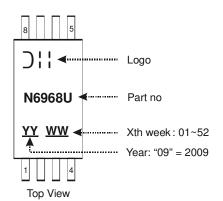
G1

Notes: 1. No purposefully added lead.

2. Diodes Inc.'s "Green" policy can be found on our website at http://www.diodes.com.

3. For packaging details, go to our website at http://www.diodes.com.

Marking Information





Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V _{DSS}	20	V
Gate-Source Voltage			V _{GSS}	±12	V
Continuous Drain Current (Note 4)	Steady State	T _A = 25°C T _A = 70°C	ID	5.2 3.5	А
Pulsed Drain Current			I _{DM}	30	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	PD	1.0	w
Thermal Resistance, Junction to Ambient @T _A = 25°C	R _{eJA}	125	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	0°

Electrical Characteristics @T_A = 25°C unless otherwise specified

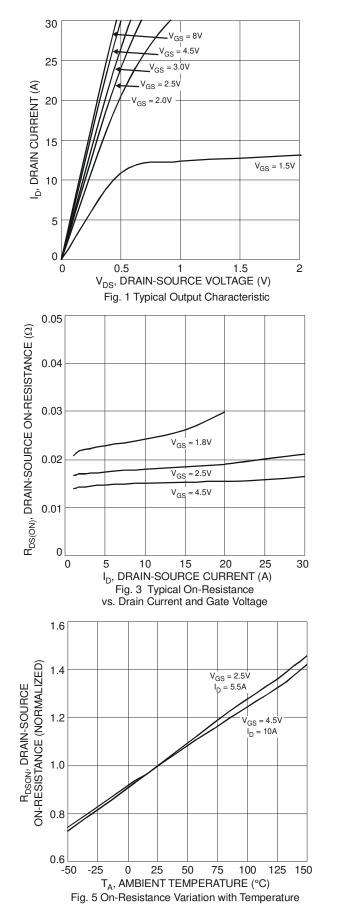
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 5)			- 76				
Drain-Source Breakdown Voltage	BV _{DSS}	20	-	-	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	-	-	1.0	μA	$V_{DS} = 20V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	-	-	10	μA	$V_{GS} = \pm 10V, V_{DS} = 0V$	
Gate-Source Breakdown Voltage	BV _{SGS}	±12	-	-	V	$V_{DS} = 0V, I_G = \pm 250 \mu A$	
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	V _{GS(th)}	0.35	-	0.95	V	$V_{DS} = V_{GS}, I_D = 250 \mu A$	
		-	18	23		$V_{GS} = 4.5V, I_D = 6.5A$	
Static Drain-Source On-Resistance	R _{DS} (ON)	-	21	27	mΩ	$V_{GS} = 2.5V, I_D = 5.5A$	
		-	26	34		$V_{GS} = 1.8V, I_D = 3.5A$	
Forward Transfer Admittance	Y _{fs}	-	13	-	S	$V_{DS} = 5V, I_D = 5A$	
Diode Forward Voltage	V _{SD}	-	0.7	1.0	V	$V_{GS} = 0V, I_{S} = 1A$	
DYNAMIC CHARACTERISTICS							
Input Capacitance	Ciss	-	143	-	pF	V _{DS} =10V, V _{GS} = 0V f = 1.0MHz	
Output Capacitance	Coss	-	74	-	pF		
Reverse Transfer Capacitance	C _{rss}	-	29	-	pF		
Gate Resistance	Rg	-	202	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge	Qg	-	8.8	-	nC		
Gate-Source Charge	Q _{gs}	-	1.4	-	nC	$V_{GS} = 4.5V, V_{DS} = 10V,$ $I_D = 6.5A$	
Gate-Drain Charge	Q _{gd}	-	3.0	-	nC		
Turn-On Delay Time	t _{D(on)}	-	53	-	ns		
Turn-On Rise Time	tr	-	78	-	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$ $R_L = 10\Omega, R_G = 6\Omega$	
Turn-Off Delay Time	t _{D(off)}	-	562	-	ns		
Turn-Off Fall Time	tf	-	234	-	ns	7	

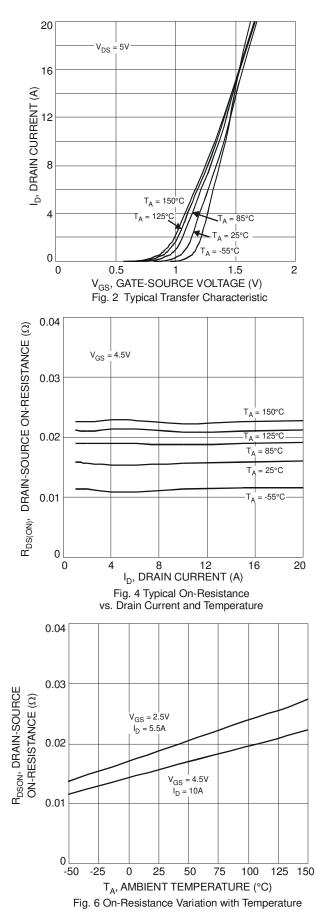
Notes:

Device mounted on FR-4 PCB.
Short duration pulse test used to minimize self-heating effect.

DMG6968UTS

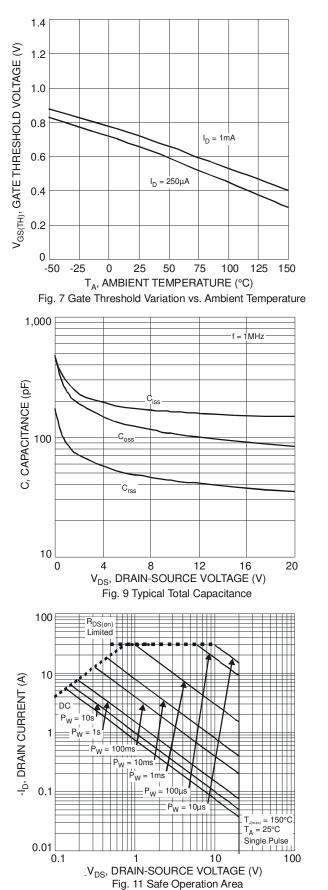


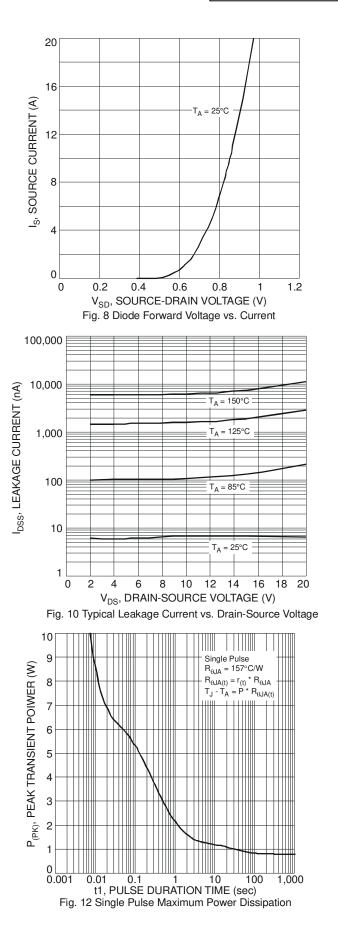




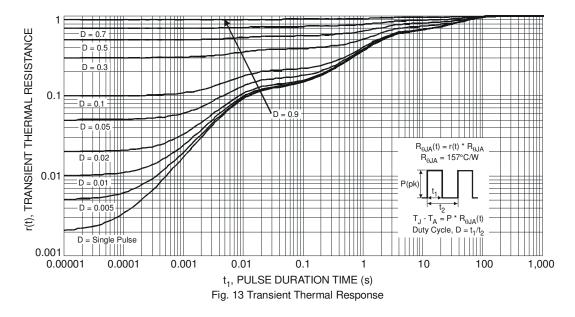
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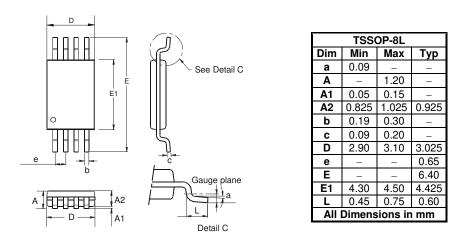




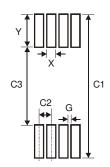




Package Outline Dimensions



Suggested Pad Layout



Dimensions	Value (in mm)
Х	0.45
Y	1.78
C1	7.72
C2	0.65
C3	4.16
G	0.20



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